

Spin-Wave Modes in Transition from a Thin Film to a Full Magnonic Crystal

M. Langer,^{1,2} R. A. Gallardo,³ T. Schneider,^{1,4} S. Stienen,¹ A. Roldán-Molina,⁵

Y. Yuan,¹ K. Lenz,¹ J. Lindner,¹ P. Landeros,³ and J. Fassbender^{1,2}

¹*Helmholtz-Zentrum Dresden – Rossendorf, Institute of Ion Beam Physics and Materials Research,
Bautzner Landstr. 400, 01328 Dresden, Germany*

²*Institute for Physics of Solids, Technische Universität Dresden, Zellescher Weg 16, 01069 Dresden, Germany*

³*Departamento de Física, Universidad Técnica Federico Santa María,
Avenida España 1680, 2390123 Valparaíso, Chile*

⁴*Department of Physics, Technische Universität Chemnitz,
Reichenhainer Str. 70, 09126 Chemnitz, Germany*

⁵*Instituto de Física, Pontificia Universidad Católica de Valparaíso, Avenida Brasil 2950, 2390123 Valparaíso, Chile*
(Dated: February 23, 2017)

Spin-wave modes are studied under the gradual transition from a flat thin film to a ‘full’ (one-dimensional) magnonic crystal. For this purpose, the surface of a pre-patterned 36.8 nm thin permalloy film was sequentially ion milled resulting in magnonic hybrid structures, referred to as surface-modulated magnonic crystals, with increasing modulation depth. After each etching step, ferromagnetic resonance measurements were performed yielding the spin-wave resonance modes in backward-volume and Damon-Eshbach geometry. The spin-wave spectra of these hybrid systems reveal an even larger variety of spin-wave states compared to the ‘full’ magnonic crystal. The measurements are corroborated by quasi-analytical theory and micromagnetic simulations in order to study the changing spin-wave mode character employing spin-wave mode profiles. In backward-volume geometry, a gradual transition from the uniform mode in the film limit to a fundamental mode in the thin part of the magnonic crystal was observed. Equivalently, the first and the second film modes are transform into a center and an edge mode of the thick part of the magnonic crystal. Simple transition rules from the n^{th} film mode to the m^{th} mode in the ‘full’ magnonic crystal are formulated unraveling the complex mode structure particularly in the backward-volume geometry. An analogous analysis was performed in the Damon-Eshbach geometry.

I. INTRODUCTION

Periodically patterned magnetic materials with periodicities ranging from micrometers down to several tens of nanometers are referred to as magnonic crystals (MCs).^{1–8} In the last decade, this group of meta-materials, such as bi-component systems,^{9–14} free standing structures,^{15–20} and continuous films with periodic structures on top (surface-modulated magnonic crystals),^{21–26} experienced a growing scientific interest. As spin waves (SWs) offer unique properties such as charge-less propagation and high group velocities, there are multiple applications conceivable since industry is in need for higher efficiencies as well as high performances in information technology including the transport and processing of data.^{8,27–36}

The possibility to manipulate the band gaps^{9,37–43} and to tailor the SW properties paves the way for many magnonic applications,⁴⁴ such as magnonic filters,⁴⁵ logical circuits^{29,30,46,47} and magnonic grating couplers.¹¹ Moreover, fast developments in spintronics and spin-caloritronics⁴⁸ hold out the perspective of many novel promising hybrid-topics⁸ in the future, where the unique properties of MCs are combined with functional entities, such as recently shown for spin-torque oscillators.⁴⁹

This work focuses on the understanding of the transition of SW modes from the film limit to the limit of a one-dimensional MC. All transitional states consisting of periodic array of wires on top of a thin film are referred

to as surface-modulated magnonic crystal (SMMC). The transitional SMMCs are fabricated by sequential ion milling of a lithographically surface-patterned permalloy (Ni₈₀Fe₂₀) thin film offering the benefit of studying the transition gradually on the same sample. Subsequent to each ion-milling step, broadband ferromagnetic resonance (FMR) measurements are performed and corroborated by micromagnetic simulations and quasi-analytical theory.

In an ongoing miniaturization process, future devices will require small SW wavelengths below 100 nm in an exchange-dominated regime. For this reason, a base periodicity of $a_0 = 300$ nm, and an individual nominal wire width of approximately $w = 140$ nm was chosen, i.e., characteristic SW mode wavelengths in this system are ranging from 60 to 300 nm. Even though, there are other advanced methods to investigate such transition, as e.g. thermal landscape modulation⁵⁰ or periodic Oersted-fields of current-carrying meander structures,⁵¹ these approaches are so far non-applicable to periodicities of 500 nm and below.

Up to now the two limits — the thin film limit^{21,22,24,26} and the ‘full’ MC^{37,39,40,52–57} — are already intensively studied. This work is focused on the properties of transitional systems offering even richer spectra of SW states with adjustable SW amplitudes. However, the huge variety of modes in SMMCs, the strong coupling between them, and the distortion of the mode profiles due to the inhomogeneous internal demagnetizing fields hinder a straightforward interpretation of the mode charac-

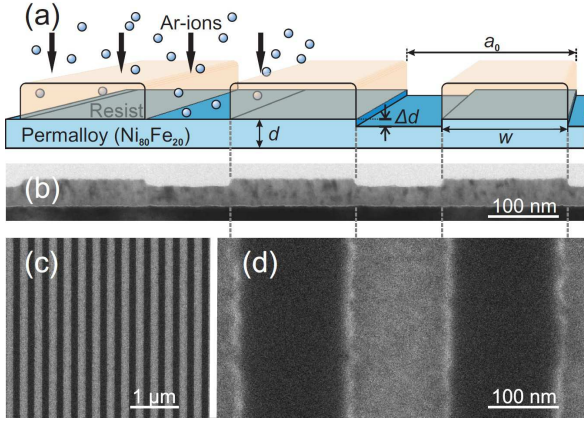


FIG. 1. (Color online) (a) Sketch of the sequential fabrication of several SMMCs by ion-milling of a single sample. (b) TEM image of a sample milled to $\Delta d = 10$ nm surface modulation. (c-d) SEM images of the top view of the same sample before the removal of the resist mask.

ter. This is where the approach to follow the modes of SMMCs with an increasing modulation height becomes particularly favorable in order to disentangle these effects.

The manuscript is organized as follows. Detail about the sample fabrication and the measurement technique are specified in Sec. II followed by Sec. III and Sec. IV containing the results for the backward-volume and the Damon-Eshbach geometry, respectively. At last, a brief summary is provided in Sec. V.

II. EXPERIMENT

The experiments are based on a single polycrystalline $d = 36.8$ nm thin permalloy ($\text{Ni}_{80}\text{Fe}_{20}$) film deposited by electron beam deposition on surface-oxidized Si(001) substrate. The surface of the film was lithographically stripe patterned using ma-N 2401 negative resist. In order to stepwise remove the magnetic material between the resist-covered stripes, sequential Ar-ion milling was employed. The procedure is schematically depicted in Fig. 1(a). Figures 1(b)–(d) show the corresponding cross-section and top view of a patterned permalloy film after the milling of $\Delta d = 10$ nm. Altogether, the film was milled five times until an array of separate wires, i.e. a ‘full’ MC, was achieved.

After each ion-milling step, the frequency-field-dependence $f(H_0)$ was measured using a broadband ferromagnetic resonance (FMR) setup, as described in reference [26]. An FMR pre-characterization of the thin film properties was carried out prior to the sequential ion milling yielding the magnetic polarization $\mu_0 M_S = 0.9236$ T, the g -factor $g = 2.11$ and the exchange stiffness $D = 23.6$ Tnm².^{26,58} It shall be noted that the investigations concentrate on symmetric modes only, since the dynamic measurements are carried out using a symmetric

excitation method.

The etching depths of each SMMC was determined by fitting of the $f(H_0)$ dependence of SW modes standing vertically in the film, also referred to as perpendicular standing spin-wave (PSSW) modes.^{59,60} For larger modulation heights $\Delta d > 10$ nm, vibrating sample magnetometry measurements were employed to determine the magnetic volume of an etched reference film before (M_1) and after (M_2) the ion milling step. This approach estimates the modulation height $\Delta d = d \times (1 - M_2/M_1)$ with the ratio of the measured magnetic volume M_2/M_1 .

The following discussion of SW modes in SMMCs is subdivided by the in-plane orientation of the external field with respect to the modulation axis of the SMMC, i.e. backward-volume and Damon-Eshbach geometry.

III. BACKWARD-VOLUME GEOMETRY

SWs in an SMMC with field orientation parallel to the modulation axis, i.e. $\mathbf{k} \parallel \mathbf{M}$ (referred to as backward-volume geometry), are particularly interesting due to the highly inhomogeneous demagnetizing fields $\mathbf{H}_d$, which are largest compared to all other in-plane field orientations. Before different transitional SMMCs are addressed, both, the planar film limit as well as the limit of a ‘full’ MC of separate wires shall be addressed.

In order to understand the complex mode structure of the SMMCs, micromagnetic simulations were carried out using the MuMax3-code.⁶¹ For all simulations, the material parameters presented in Sec. II were re-employed and several SMMCs were micromagnetically reconstructed using a fixed film thickness of $d = 36$ nm and six modulation heights of $\Delta d = 2, 4, 9, 13.5, 18$ and 36 nm with the latter representing the ‘full’ MC. For the realization of an extended MC, periodic boundary conditions were applied to the in-plane axes. To obtain the spin-wave spectra of each SMMC, a pulsed excitation⁶² was realized and the integral dynamic magnetization was plotted as the FMR response.

A. The Limits: Thin Film and Full Magnonic Crystal

Thin Film Limit. The film limit has previously been studied in experiment^{21,26,63} and theory using two-magnon scattering perturbation theory.^{22,24} It is coherently found that for SMMCs with small modulation height, the demagnetizing field H_d has only substantial field strength at the relatively small edges on the film surface and is negligible in the volume of the structure. Thus, H_d acts as a small periodic perturbation introducing a base periodicity a_0 crucial for the presence of standing SW modes. While the dispersion remains unaffected, an introduction of periodic perturbations in the real space leads to a discretization of standing SW modes

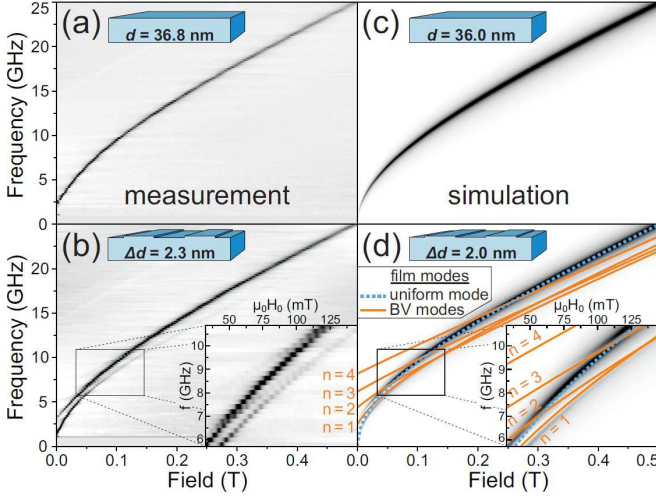


FIG. 2. (Color online) Measurement and simulation of the frequency-field dependence of (a),(c) a flat film and (b),(d) a surface-modulated magnonic crystal with tiny modulations ($\Delta d = 2$ nm). Orange lines represent the spin waves' frequency-field dependences calculated from Eq. (1).

in the k -space according to $k = 2\pi n/a_0$ with k being the in-plane wave vector and $n = 1, 2, 3, \dots$. As mentioned above, the SW dispersion follows the well known relation:⁶⁴

$$\left(\frac{\omega}{\gamma}\right)^2 = (\mu_0 H_0 + Dk^2) \times \left[\mu_0 H_0 + \mu_0 M_s \left(\frac{1 - e^{-kd}}{kd} \right) + Dk^2 \right] \quad (1)$$

with $f = \omega/(2\pi)$ the FMR frequency.

Equation (1) yields a parabolic shape of the dispersion for dipole-exchange spin waves in backward-volume geometry. The characteristic shape implies an energy degeneracy, which together with the scattering condition $k = 2\pi n/a_0$ enables the two-magnon scattering channel from the uniform mode to the $k \neq 0$ standing SW modes.

In Figs. 2(a),(c), the measured and the simulated frequency-field dependences $f(H_0)$ are depicted for a flat film and in Figs. 2(b),(d) for an SMMC with 2 nm modulation height. Fig. 2(d) additionally provides the $f(H_0)$ dependence of the $n = 1 \dots 4$ modes calculated from Eq. (1) and plotted as orange solid lines. Clearly, standing SW modes in an SMMC with tiny modulation follow the $f(H_0)$ dependence of propagating modes in a flat film of the same properties quite well. However, deviations from the film limit can be observed in the vicinity of crossing points in the $f(H_0)$ dependence, where different standing SW modes couple to each other.

In analogy to coupled oscillators in mechanics, both modes split up into an acoustical and an optical branch with in-phase and anti-phase oscillation, respectively. The evolving gap between acoustical and optical mode is connected with a band gap formation in the k -space

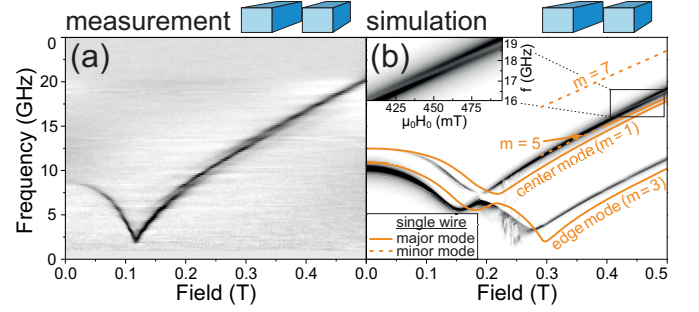


FIG. 3. (Color online) (a) Measurement and (b) simulation of the frequency-field dependence of an array of wires (one-dimensional MC) with the orange lines indicating the simulated resonance branches of a single wire of same properties. The *edge* mode is clearly suppressed in the measurement due to beveled edges and the roughness of the measured sample.

and thus, with the transition from film physics to the physics of MCs.

Full MC. The opposite limit is the periodic array of wires, also known as 'full' or one-dimensional MC,^{5,10} with the $f(H_0)$ dependence shown in Fig. 3. Figure 3(a) is the measurement and 3(b) the simulation with orange lines indicating the simulated resonance modes of a single wire.

If the stray field contribution of neighboring wires (approximately 30 mT) is considered to shift the modes to lower resonance fields, both the MC (colorplot in Fig. 3(b)) and the single wire (orange lines in Fig. 3(b)) reveal very similar results for the given dimensions. Due to the strong locally varying internal demagnetizing fields, different fundamental modes can be excited, namely the *wire* and the *edge* mode. Above, there are also higher order modes standing within the boundaries of the structure. Note that a symmetric excitation only allows for the measurement of symmetric SW eigenmodes and due to symmetry arguments, the peak number m of SW modes in the 'full' MC limit must be odd ($m = 1, 3, 5, \dots$).

The mode profiles corresponding to each resonance branch in Fig. 3(b) are shown in Fig. 4 at an external field of 300 mT. The two fundamental branches can be identified as the *edge* mode ($m = 3$) in Fig. 4(a) and the *wire* mode ($m = 1$, also termed 'wire center mode') in Fig. 4(b), where the former appears to be completely suppressed in the measurement due to the beveled edge shape and edge roughness of the sample. Figures 4(c),(d) reveal the mode profiles of higher modes ($m = 5, 7$) standing within the boundaries of the wire. These modes only carry significant intensities while crossing one of the fundamental branches to which they couple (see the inset in Fig. 3(b)).

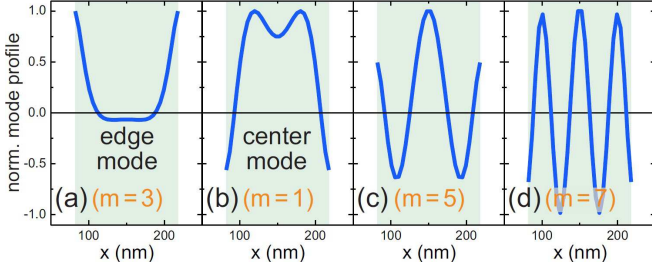


FIG. 4. (Color online) Mode profiles in an array of wires in backward-volume geometry (as shown in Fig. 3(b)) at 300 mT.

B. Transitional SMMCs

The sequential ion-milling was performed with very small etchings steps in the beginning ($\Delta d \rightarrow 0$) and large etching steps in the end ($\Delta d \rightarrow d$). This is due to the demagnetizing field increasing substantially in the range of $\Delta d = 0 - 10$ nm (see inset Fig. 5) and gradually saturating above that range. For SMMCs with larger modulation heights, the changes become less significant with Δd and thus, the alteration of the mode character is uncritical.

Figure 5 shows the $f(H_0)$ plots of several SMMCs with a modulation height Δd in the range of 2.0–13.5 nm. In Figs. 5(a)–(d) and 5(e)–(h), the FMR measurements and the simulations are illustrated, respectively. In the inset, the level of the modulation is provided together with the x -component of the simulated internal demagnetizing field $H_{d,x}$ as colorplot. Inside the thick part (also termed ‘wire’) of the MC, the demagnetizing field acts *against* (negative sign) the local magnetization direction as usually. Interestingly, inside the thin part (also ‘trench’), it acts *with* the magnetization and is, thus, a *magnetizing* field. The increasing contrast between the *magnetizing*- and demagnetizing fields with the modulation height is easily inferred from the insets in Figs. 5(e)–(h). This effect is important for the understanding of the evolution of SW modes in SMMCs with increasing modulation height Δd .

It is again distinguished between fundamental modes and higher order SW modes. The former can be directly excited uniformly whereas the latter gain intensity from coupling to a fundamental branch. In Figs. 5(e)–(h), fundamental modes are marked by dashed colored lines. The color of each mode is chosen corresponding to the $H_{d,x}$ field where orange color represents *magnetizing* fields and blue color demagnetizing fields.

Prior to a detailed discussion, a splitting into two fundamental modes, a SW excitation in the trench (*trench mode*) and an excitation of the wire (*wire mode*), can already be concluded. Now, due to the increasing contrast between the (de-)magnetizing fields in the trench and in the wire, both modes undergo a vast separation leading to the evolution of a large gap between them (see Figs. 5(g) and 5(h)). Next, the transition of each SW

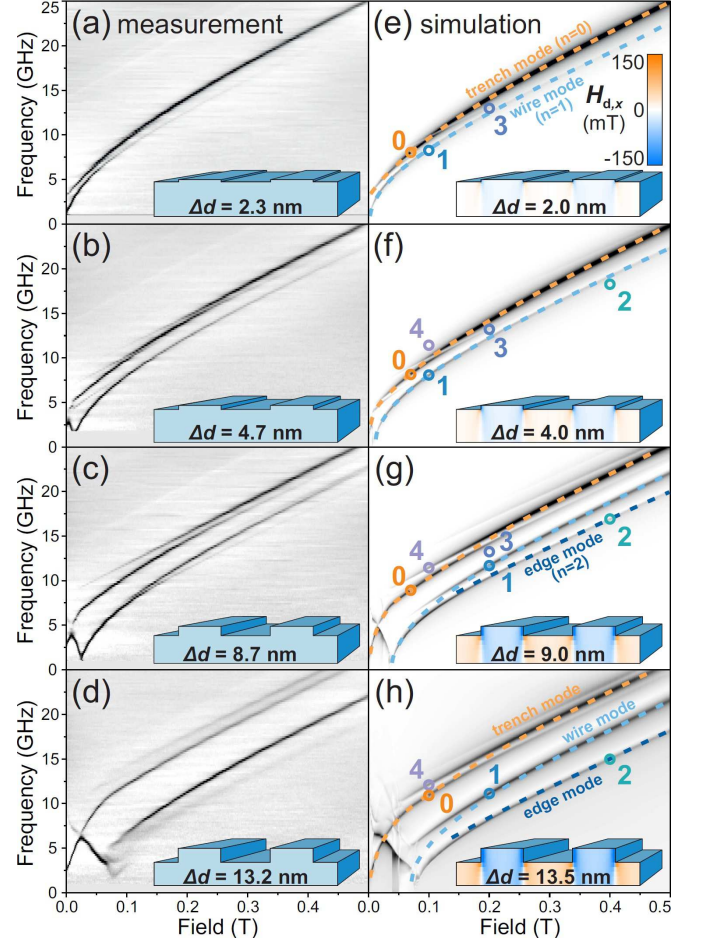


FIG. 5. (Color online) (a)–(d) FMR measurements of MCs with different modulation heights as sketched in the insets. (e)–(h) The dynamic response with the internal demagnetizing field in the inset both calculated using pulsed micromagnetic simulations. Colored dots represent the field-frequency position of the mode profiles illustrated in Fig. 6.

mode from the film to the ‘full’ MC shall be addressed.

Quasi-Uniform Mode. A comparison between the uniform mode in the film limit (blue dotted line in Fig. 2(d)) and the $n = 0$ mode in SMMCs (orange dashed line in Fig. 5(e)) reveals the transition of the uniform mode to a localized quasi-uniform excitation of the thin part of the SMMC (here termed *trench mode*). The transition of the mode character can be understood best with the help of Fig. 6 where the Δd -dependent mode profiles at the marked resonance positions in Fig. 5 are displayed. Figure 6(a) shows the mode profiles of the *trench mode* ($n = 0$) within one period a_0 . Moreover, a colorplot of the Δd -dependent mode amplitude within the trench region can be found in Fig. 6(f).

A clear maximum in the center of the trench is observed, which becomes more confined with increasing modulation height. Moreover, the amplitude in the wire region vanishes as Δd increases. These observations are

evidences for a transition from the uniform mode towards a quasi-uniform ($k = 0$) excitation of the trench center, which vanishes if the trench is completely removed.

The confinement of the center peak of the *trench* mode is explicitly explained in Ref. [58] and increasing with Δd . The effect is connected with the diverging internal H_d fields. For spins in neighboring regions to the trench center, the higher internal fields shift the solution of the SW dispersion in Eq. (1) to $k \neq 0$. And due to an increasing internal field contrast, the local k -vector becomes larger with Δd leading to a narrowing of the center peak.

1st SW Mode. The bright blue dashed lines in the Figs. 5(e)–(h) indicate the *wire* mode. Originating from the 1st standing SW mode in the film limit (see $n = 1$ mode in inset of Fig. 3(d)), this mode evolves from a sinusoidal harmonic standing SW mode to one central peak localized inside the wire region. The mode profiles in Figs. 6(b) and 6(g) demonstrate this transition.

The reason for the modes' confinement in the wire region lies in the energy of the mode in the film limit. Being below the uniform mode in the $f(H_0)$ dependence (Fig. 2(b)), the energy of the 1st SW mode is insufficient for an excitation of the complete SMMC. Thus, the mode localizes in regions, where the energy is internally reduced due to the presence of a demagnetizing field. In regions with *magnetizing* fields (e.g., the trench), this mode becomes strongly damped.

It shall be mentioned that the *wire* mode is of a different nature than the *trench* mode with respect to the local k -vector. Even though both modes exhibit a similar shape within the respective region, the *wire* mode is localized at a local maximum of the internal H_d field, whereas the *trench* mode is excited at a local minimum. As mentioned above, for small wavelength excitations, the k -vector locally rises with higher internal fields and in-turn, drops with lower internal fields due to Eq. (1).⁵⁸ So, if the center of the wire was excited quasi-uniformly ($k = 0$), like in case of the *trench* mode, there would be no possible solution solving Eq. (1) for the neighboring spins, which are exposed to a reduced H_d field. This would immediately damp out this mode. Hence, the fundamental *wire* mode must exhibit a $k \neq 0$ excitation in the center, and hence, should be interpreted as an $m = 1$ standing spin-wave mode within the wire region.

Eventually, mode 1 is following the transition from an $n = 1$ film mode to an $m = 1$ mode in the 'full' MC.

2nd SW Mode. With moderate modulation heights of $\Delta d \approx 10$ nm, the 2nd SW mode in the film limit starts to gain intensity, as illustrated in the Figs. 5(g) and 5(h), and evolves towards an *edge* mode inside the wire region. This transition is again reflected by the mode profiles in the Figs. 6(c) and 6(h).

In general, two transformations are observed. (i) The localization of $2n - 1 = 3$ nodes inside the wire and subsequently, (ii) the suppression of the central peak and the localization at the wire edge. The reason for (i) is equiv-

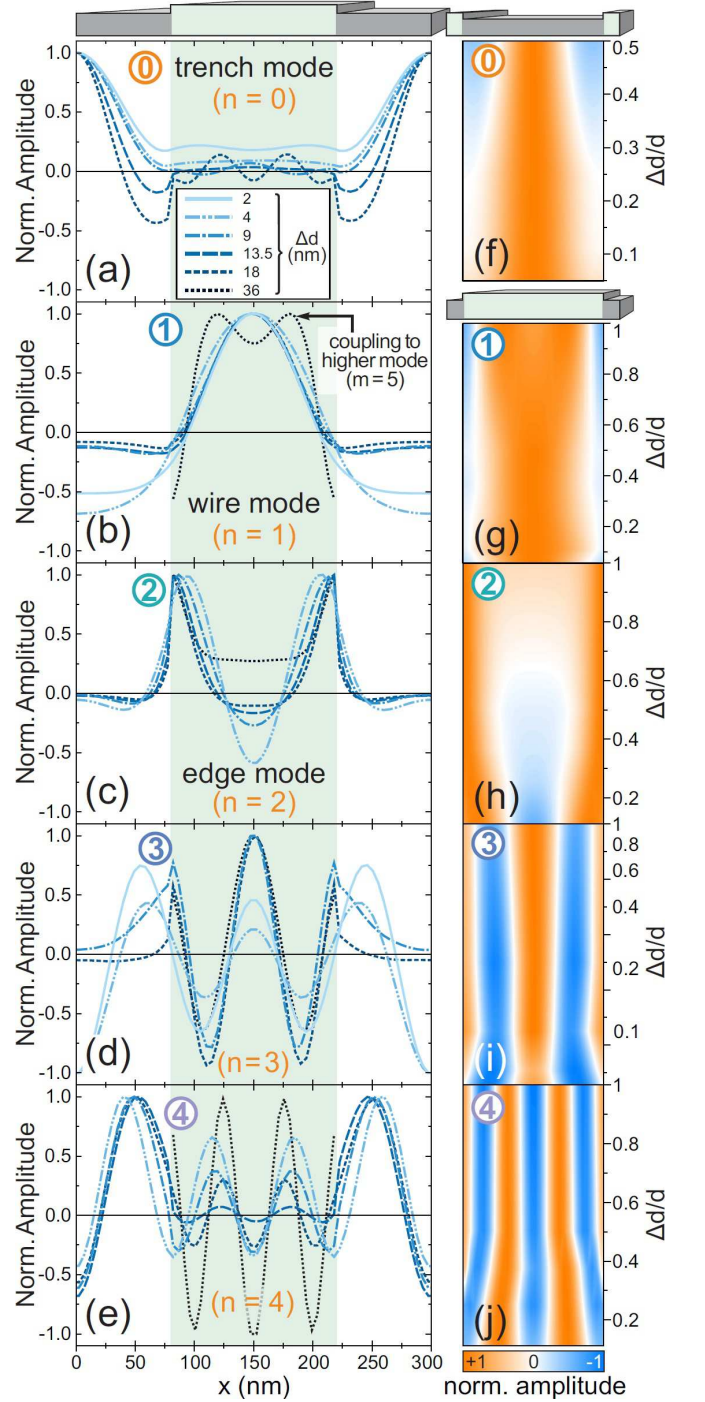


FIG. 6. (Color online) (a)–(e) Mode profiles at the marked resonance positions in Fig. 5 revealing the transitional states between the film limit and the limit of an array of wires. (g)–(j) The modulation-height dependent normalized mode profiles inside the wire region being an important proof for the transition from the n^{th} film mode to the m^{th} mode in the 'full' MC limit.

alent to the explanation for the localization of the *wire* mode. In the film limit, the 2nd SW mode lies even below the 1st mode (at fields above 100 mT) with the same

consequence, the mode cannot extend over the ‘full’ MC and localizes with $m = 3$ peaks within the wire region instead. The reason for (ii) is due to the formation of a distinct spin-wave well,⁶⁵ i.e. a local minimum of $H_d(x)$, coinciding with the outermost peaks of this mode close to the wire edge. Since the energy of the mode is lowest below the trench and the *wire* mode, the excited resonant region must be of lower energy, which is only the case at the wire edge. Thus, the mode profiles of the second mode in Fig. 6(c) are interpreted as a transition from the $n = 2$ mode to an $m = 3$ mode with increasing mode localization at the edges and decreasing amplitude (mode damping) at the wire center.

Higher Order Modes. Higher order ($n > 2$) spin-wave modes are also present throughout the transition from a film to a ‘full’ MC. And as mentioned before, these modes only carry intensity when crossing one of the fundamental modes (see Fig. 5) and coupling to them. Thus, these modes exhibit quite different mode profiles depending on whether they couple to the trench or to the *wire* mode. In the former case, the modes reveal major amplitude inside the thin part of the MC and in the latter the amplitudes concentrate inside the thick part (see profiles of mode 3 and 4 in Fig. 6(d),(e)). However, for the transition to the ‘full’ MC, the Δd -dependent amplitude inside the wire is crucial revealing a steady evolution of the mode character to the ‘full’ MC. This steady process is depicted in Fig. 6(i),(j).

Generally, it is observed, that film modes localize $m = 2n - 1$ peaks within the wire region during this transition process. Together with a single ‘silent’ (damped) minimum in the center of the trench, the total number of $2n$ peaks within one period a_0 is conserved throughout this process. In some cases, like for mode 3 and 4, the mode profiles in the ‘full’ MC (see Figs. 4(c),(d)) rather appear as $m = 3$ and $m = 5$ modes instead of $m = 5$ and $m = 7$. In both cases, the last peaks at the edges are incomplete raising the question whether they contribute or not to the peak number m in the limit of the ‘full’ MC. To answer this question, it is useful to identify their role in the transition to the ‘full’ MC. Take for example the 3rd mode at $\Delta d = 18$ nm (see Fig. 6(d)). Only when both edge peaks are fully taken into account, the total number of nodes within one period remains 6, making n a conserved quantity. At this stage of the transition, the modes’ profile inside the wire region is already set and since both peaks amplitude is clearly damped outside the wire, they should fully contribute to the mode number $m = 5$ inside the wire.

Certainly, modes of a high peak number m tend to cut off their edge peaks, since in that way, the high cost of exchange energy $Dk^2 \propto (m/w)^2$ is minimized when condensing $2n - 1$ peaks within the narrow wire region. Thus, the individual pinning of the m^{th} mode at the wire edges is likely depending on the width w of the wire. This is supported by the mode profiles shown in Ref. [58] where an SMMC of a different wire width w , but with the

same periodicity $a_0 = 300$ nm, thickness $d = 36.8$ nm and material parameters was analyzed. This MC exhibited a significantly larger nominal wire width of $w = 166$ nm resulting in similar mode characteristics with a different pinning condition at the wire edges.

It is coherently observed that the n^{th} film mode evolves into the m^{th} mode in the ‘full’ MC with $m = 2n - 1$. Only the $n = 0$ mode maintains a local quasi-uniform ($n = 0$) character and does not follow this general rule. This observation is believed to reflect the momentum quantization of standing SW modes throughout this process allowing only for even numbers of $2n$ nodes and peaks within one period a_0 .

IV. DAMON-ESHBACH GEOMETRY

In the Damon-Eshbach orientation ($\mathbf{k} \perp \mathbf{M}$) when the field is applied parallel to the surface edges, standing SW modes are also present. For the sake of completeness, the measurement results for this orientation are provided as well. However, the micromagnetic part of the study will reveal that major changes of the mode character occur at a very high level of surface modulation where the experimental data remains incomplete.

A. The Limits: Thin Film and Full Magnonic Crystal

Thin Film Limit. In contrast to the backward-volume orientation, there is no energy degeneracy in the Damon-Eshbach orientation. For this geometry, the dispersion reads^{24,64}

$$\left(\frac{\omega}{\gamma}\right)^2 = \left[\mu_0 H_0 + \mu_0 M_S \left(1 - \frac{1 - e^{-kd}}{kd} \right) + Dk^2 \right] \times \left[\mu_0 H_0 + \mu_0 M_S \left(\frac{1 - e^{-kd}}{kd} \right) + Dk^2 \right]. \quad (2)$$

Hence, there are no scattering channels present to transfer intensity from the uniform mode to a $k \neq 0$ standing SW mode. This is why Damon-Eshbach modes are of no (or extremely small) intensities for small modulation heights Δd in contrast to standing spin-wave modes in backward-volume orientation. A prominent level of modulation in the magnitude of $d/4$ was found to be necessary for the detection of at least a small intensity of the 1st mode. Thus, the film limit in Damon-Eshbach geometry is governed by the unaltered uniform mode.

Full MC. In this limit, the main mode (here termed *wire* mode) can be calculated using the demagnetizing factor of the wires^{57,66}

$$\left(\frac{\omega}{\gamma}\right)^2 = [\mu_0 H_0 + N_x \mu_0 M_S] \times [\mu_0 H_0 - N_x \mu_0 M_S + \mu_0 M_S] \quad (3)$$

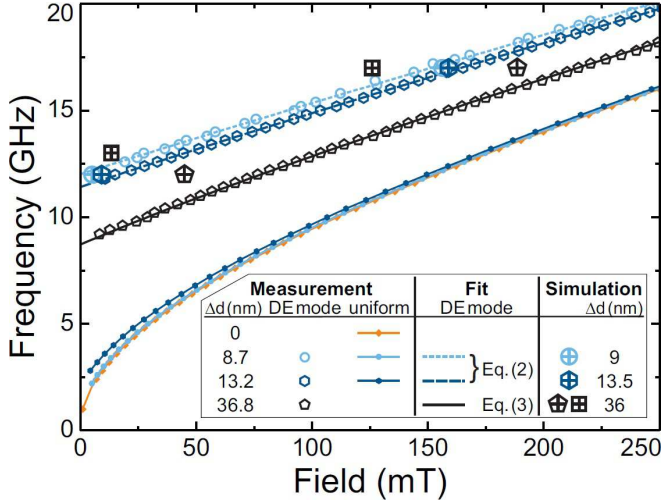


FIG. 7. (Color online) Measurement of the frequency-field dependences of the 1st Damon-Eshbach mode (open symbols) for the modulation heights $\Delta d = 8.7$ nm, 13.2 nm and 36.8 nm with fits (dashed and solid lines). Crossed symbols represent the results of micromagnetic simulations. The standard material parameters were used as fitting parameters yielding an effective thickness $d = 27.6$ nm and 23.0 nm for $\Delta d = 8.7$ nm, and 13.2 nm. In case of the ‘full’ magnonic crystal, the fit yields a demagnetizing factor of $N_x = 0.115$.

With N_x being the demagnetizing factor along the wire in-plane short (x -) axis and with the shape-anisotropy $N_x \mu_0 M_S$. These modes can be expressed by Eq. (2) with the wavevector being quantized with $k = m\pi/w$, $m = 1, 3, 5, \dots$ due to a defined number of nodes fitting inside the wire width w . Note that the pinning at the wire edges can strongly influence the $f(H_0)$ dependence of the mode. Therefore, a modified mode number $m \rightarrow m + \lambda$ can be defined with λ being the pinning parameter leading to a higher accuracy of the resonance positions.⁵⁷

In case of the measurements carried out in this work, only the *wire* mode was detected (black open pentagons in Fig. 7). However, micromagnetic simulations (black crossed pentagons and squares in Fig. 7) reveal the existence of higher ($m > 1$) modes with small intensity. The simulated resonance position of the second highest intensity mode with $m = 3$ (termed ‘*edge mode*’) is also shown (crossed squares) in Fig. 7 where the crossed pentagons represent the $n = 1$ (*wire*) mode.

B. Transitional SMMCs

In the experimental study, the first measurable intensity of an $n = 1$ Damon-Eshbach mode was detected for $\Delta d = 8.7$ nm (circles in Fig. 7). At a modulation height of $\Delta d = 13.2$ nm, the mode gains intensity and is slightly shifted to lower frequencies and higher field values. In general, this is what one would expect from Eq. (2), since with lower effective film thickness d the

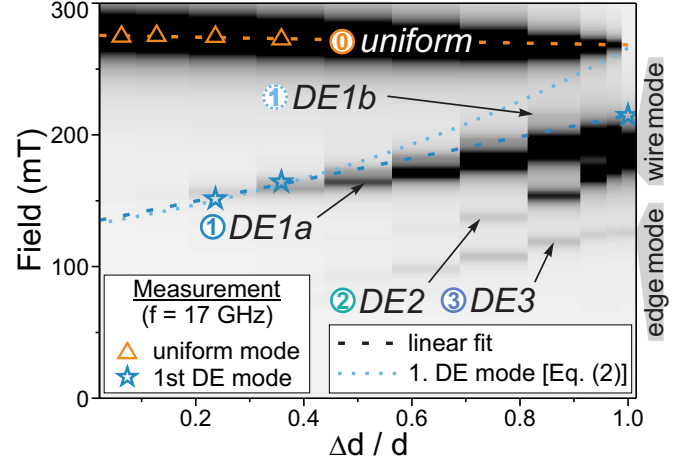


FIG. 8. (Color online) Micromagnetic Simulation of the SW resonances at $f = 17$ GHz depending on the modulation height Δd in Damon-Eshbach orientation. Symbols represent the results from the measurement. Note the fading uniform mode and the emerging of the *wire* mode in the ‘full’ magnonic crystal from the 1st and the 2nd spin-wave mode.

frequency of the Damon-Eshbach mode is reduced due to the reduced dipolar energy. The expected increase of the mode’s resonance field according to Eq. (2) is depicted in Fig. 8 as a blue dotted line. At a modulation height of about half the film thickness, applying Eq. (2) leads to major deviations from the measured (blue asterisks in Fig. 8) and simulated (colorplot) resonance positions. This is due to the fact that the thin-film approximation becomes increasingly inappropriate to reflect the geometrical reality.

However, micromagnetic simulations (colorplot in Fig. 8) indicate that the 1st Damon-Eshbach mode (together with the 2nd mode) evolves into a fundamental (*wire*) mode in the full magnonic crystal. At the same time, the quasi-uniform mode (orange lines and symbols in Fig. 8) gradually disappears.

In the following the mode profiles of these two main modes shall be discussed together with some higher order Damon-Eshbach modes.

Quasi-Uniform Mode. In Fig. 9 the Δd -dependent mode profiles of the quasi-uniform mode and the first three Damon-Eshbach-type standing SW modes are plotted. On the left side of Figs. 9(a)–(e), the space-dependent spin-wave amplitude is plotted, whereas the colorplots on the right side (Figs. 9(f)–(j)) reveal the effective amplitudes, i.e. the same profiles scaled with the local film thickness. In case of the $n = 0$ (quasi-uniform) mode, the dynamic activity appears to concentrate inside the thin part, which is analogous to the character of the *trench* mode in the backward-volume geometry. However, when scaled with the local film thickness, the response of both, thick and thin part remains equally high in the center of both regions. This observation is a major difference compared to the behavior of the

$n = 0$ mode in backward-volume direction. Here, in the Damon-Eshbach orientation, the effective behavior remains quasi-uniform in the *full* structure. And as the modulation becomes dominant, the effective dynamic activity is reduced close to the edges of the wire, where dynamic demagnetizing fields become relevant altering the SW dispersion. This leads to the picture illustrated in Fig. 9(f), where a constant effective SW amplitude is visible together with channels of reduced dynamic activity at the boundaries between both regions.

1st SW Mode. The colorplot in Fig. 8 reveals a splitting of the 1st SW mode into two modes. A high-intensity mode changing gradually into a *wire* mode and, closer to the dotted line corresponding to Eq. (2), another low-intensity mode. The latter fades out for high Δd . The profiles of both modes are illustrated in Figs. 9(b),(c) and 9(g),(h). Starting from the film limit, the character of both modes is dominated by the harmonic character of an $n = 1$ film mode. Only for pronounced modulations ($\Delta d \geq 27$ nm), an asymmetry within the thin part occurs in case of the low-intensity mode (Figs. 9(c),(h)), while the high-intensity mode (Figs. 9(b),(g)) remains fully symmetric throughout the whole transition. This mode keeps one peak within the thick part throughout the transition whereas the number of peaks within the thin region increases with Δd . Once the thin part of the MC is fully removed, only the peak within the thick part remains as the *wire* mode of the full MC. It shall be noted, that the origin of the low-intensity mode remains unclear but might be due to the breaking of the symmetry by the *dynamic* demagnetizing fields.

2nd SW Mode. Due to the coupling to PSSW-type modes, the mode profiles of the 2nd and 3rd Damon-Eshbach modes are significantly asymmetrically distorted. Even though the distortion causes complex time-dependent SW amplitude oscillations, the main mode character is conserved. In Figs. 9(d),(i) the $2n$ peaks of the 2nd mode are clearly identified as well as the gradual transition of the mode profile within the thick part towards the *wire* mode. In fact, the two mode profiles of the $n = 1$ and the $n = 2$ mode become less different as very high modulations are reached. For example, at $\Delta d = 35$ nm, both modes consist of a clear central peak within the thick part and another small-wavelength excitation (consisting of approximately 3 peaks) within the thin part. The only difference is that the phase of the small-wavelength excitation in the thin part is shifted around π . From this observation, it can be concluded that close to the full MC the mode character of both the $n = 1$ mode and the $n = 2$ mode is dominated by a *wire* mode character inside the thick part with an optical ($n = 2$ mode) and acoustical ($n = 1$ mode) lateral coupling low-wavelength excitation inside the thin part.

3rd SW Mode. The general mode character of the $n = 3$ mode with its $2n = 6$ peaks in total is also preserved during the transition. However inside the thick

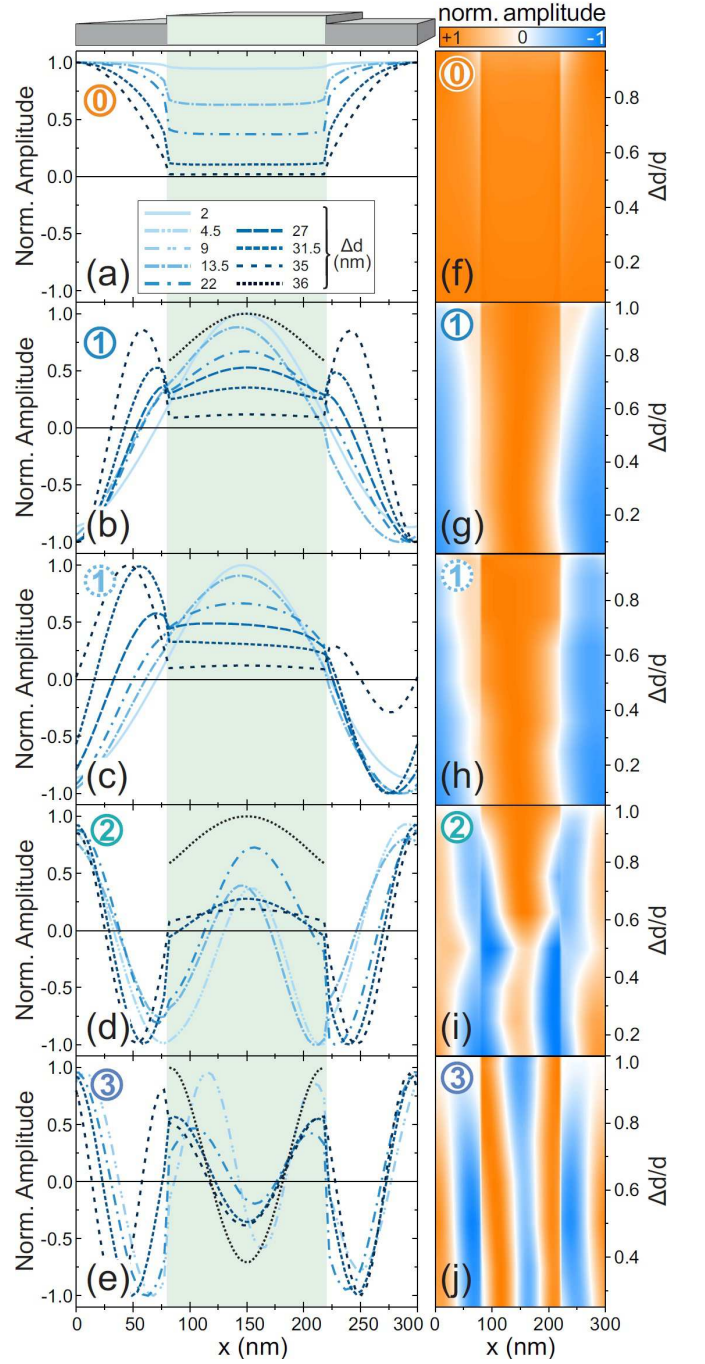


FIG. 9. (Color online) (a)–(e) Simulated spin-wave mode profiles in Damon-Eshbach geometry in the transition from a film to a full MC. (f)–(j) The Δd -dependent colorplots of the mode profiles weighted by the local film thickness.

part, this mode was observed to evolve into an *edge* mode in the full MC limit (see Figs. 9(e),(j)). The typical mode profile characteristics of this mode are already established at $\Delta d = 31.5$ nm inside the *thick* part with pronounced peaks at both edges and a smaller anti-phase peak in the center. According to the above findings for the $n = 1$ and $n = 2$ modes, one would expect the presence of an

analogous second mode close to the full MC limit with an anti-phase dynamic activity inside the *thin* part. Such mode exists in the spin-wave spectra presented in Fig. 8, but reveals a much smaller (negligible) resonance amplitude. The different behavior is due to the symmetry of the mode profile inside the thick part. The characteristic pronounced peaks at the edges of the thick part hinder the lateral coupling of an anti-phase excitation inside the thin part due to the high cost of exchange energy.

In order to summarize the transition of spin-wave modes in Damon-Eshbach geometry, it is noted that the quasi-uniform mode keeps its character throughout the transition but with a vanishing amplitude in the full MC limit where it, finally, disappears. The $n = 1$ and $n = 2$ modes are found to develop into laterally coupling acoustical and optical modes of the *wire* mode with a low-wavelength excitation inside the thin part. Moreover, the *edge* mode of the full MC gradually evolves from the $n = 3$ Damon-Eshbach mode.

V. CONCLUSION

The gradual evolution of spin-wave modes in the transition from a thin film to a full magnonic crystal has been investigated in the backward-volume and Damon-Eshbach geometry. Experimentally obtained spin-wave spectra were compared to analytical theory and micro-magnetic simulations in order to identify the modulation-height-dependent mode character. In the backward-volume orientation, an even richer spin-wave spectrum is reported compared to the full magnonic crystal. The 1st and the 2nd SW modes are found to evolve into the *wire* and the *edge* mode in the full-magnonic-crystal limit, respectively. For these modes as well as for modes of higher mode number n , general transition rules towards the m^{th} mode in the full magnonic crystal are formulated and supported by the mode profiles.

In the Damon-Eshbach orientation, major changes of the mode character are found at very high levels of surface modulation with $\Delta d \rightarrow d$. Here, the 1st and the 2nd spin-wave mode are observed to merge into the *wire* mode whereas the 3rd SW mode evolves into the *edge* mode.

VI. ACKNOWLEDGMENT

We thank B. Scheumann for the film deposition, A. Banholzer and C. Fowley for the technical support in the patterning process and P. C. Grubitz and A. Jansen for their help with the FMR measurements. The support by the Structural Characterization and Nanofabrication Facilities Rossendorf at IBC and the HZDR Department of Information Services and Computing is gratefully acknowledged. This work was supported by the Centers of Excellence with Basal/CONICYT financing (grant no. FB0807), CONICYT PAI/ACADEMIA 79140033,

FONDECYT 1161403, CONICYT PCCI (grant no. 140051), the project 111559 DGIP USM, DAAD PPP ALECHILE (grant no. 57136331) and from the Deutsche Forschungsgemeinschaft (grant no. LE2443/5-1).

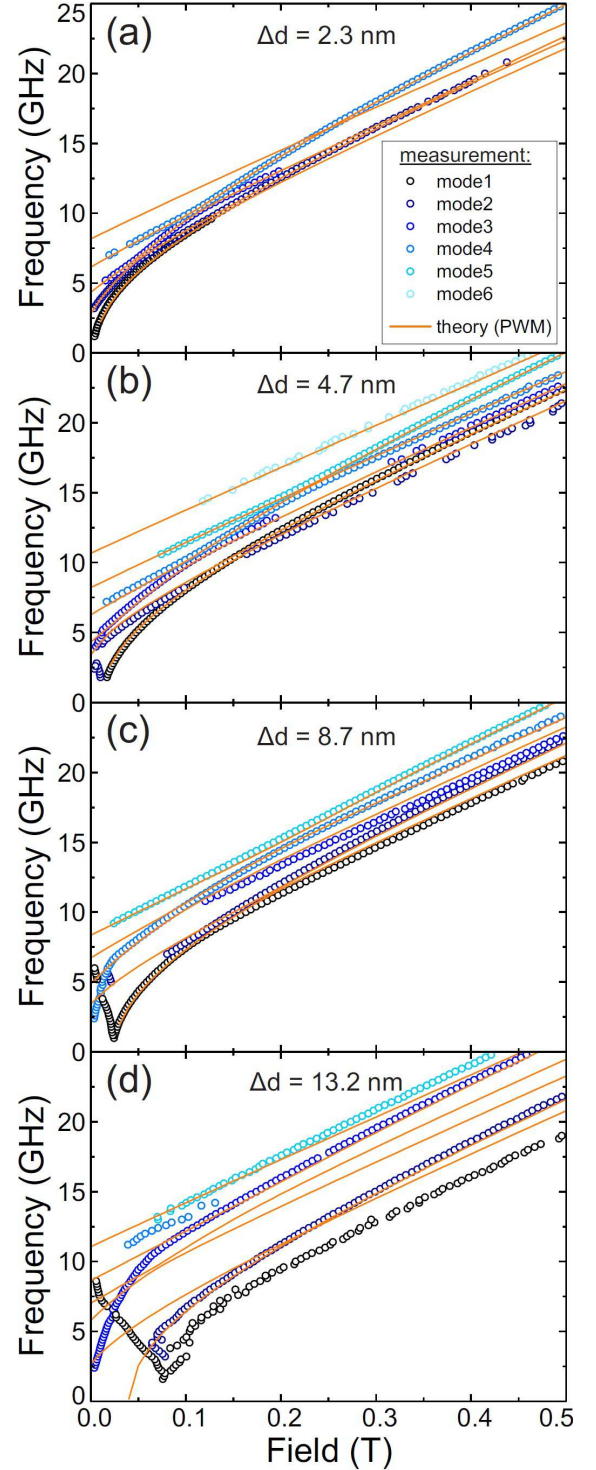


FIG. 10. (Color online) (a)–(d) Fitted spin-wave resonance spectra for different modulation heights Δd together with the quasi-analytical calculations (PWM) plotted as orange lines.

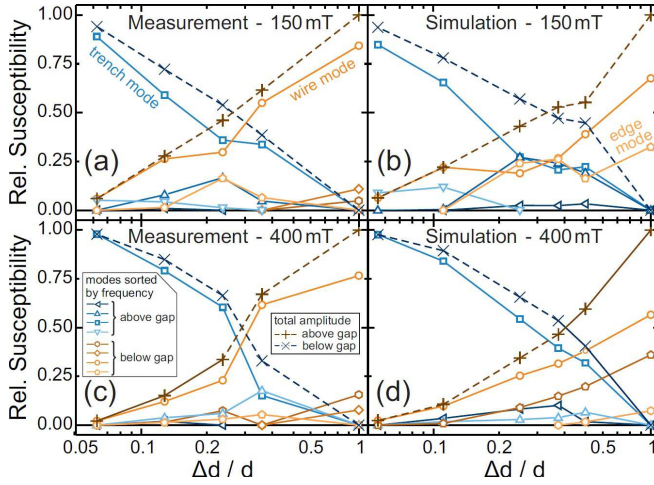


FIG. 11. (Color online) Susceptibility of the modes above the large frequency gap (blue) and below the gap (orange) dependent from the modulation height Δd . (a),(b) The susceptibility at 150 mT and (c),(d) the susceptibility at 400 mT. The measured data is shown on the left side accomplished with the simulation data on the right side.

VII. APPENDIX

(ii) Validation of the Quasi-Analytical Model

Quasi-analytical theory based on the PWM^{42,67–70} was used as well in order to understand the transition of the SW modes in backward-volume geometry. Figure 10 shows the results from PWM (orange lines) in comparison to the measurement (colored circles). The structural and magnetic parameters for the PWM-based calculations were used according to the ones selected for the micromagnetic simulations (see beginning of Sec. III). The only minor difference is that the precise Δd values listed in Fig. 10 were employed. In the simulations, these values were abstracted due to the necessity to model the SMMC by a natural number of cells. Up to the modulation

height of approximately 9 nm the agreement of theory and experiment is striking. However, for higher modulation sizes significant differences between measurement and theory are visible and are likely due to thickness-related approximations within the theory.⁷⁰ It shall be noted that up to now, such systems were theoretically handled using perturbation theory,^{22,24} which cannot be employed for such high levels of surface modulation.

The firm quantitative agreement between the numerically calculated SW resonances and the ones obtained by PWM also can be confirmed by a comparison of the mode profiles. This was already done and published elsewhere⁵⁸ confirming a very high level of agreement up to a modulation height of $\Delta d = 10$ nm.

The proven accuracy of the theory for moderate modulation heights justifies its application to calculate the spin-wave dispersion and mode profiles in the k -space. For MCs of 300 nm periodicity or less, the measurement of the SW dispersion is challenging due to the limitations associated with the maximum k -values accessible in Brillouin light scattering (BLS). That makes PWM an ideal tool regarding band-gap and band-structure analyses and optimizations for such surface-modulated MCs.

(i) Resonance Amplitude Analysis Figure 5 reveals an enriched spin-wave spectrum of SMMCs compared to the ‘full’ MC presented in Fig. 3. The dominance of the quasi-uniform *trench* mode for small Δd values and its vanishing for large values indicates the existence of a threshold where both fundamental modes, the *trench* and the *wire* mode, exhibit the same amplitude. In order to identify this threshold, an analysis of the measured and simulated mode amplitudes was carried out. Figure 11 depicts the resulting Δd -dependent amplitudes of both, measurement (11(a),(c)) and simulation (11(b),(d)) for two different field values, 150 mT (11(a),(c)) and 400 mT (11(a),(c)). In the measurement a threshold was found at approximately $\Delta d/d = 0.26$ for $H_0 = 150$ mT and $\Delta d/d = 0.29$ for $H_0 = 400$ mT. The data differs quite significantly compared to the simulation. Here, the threshold was obtained at $\Delta d/d = 0.33$ for both external field values.

¹ J. O. Vasseur, L. Dobrzynski, B. Djafari-Rouhani and H. Puzskarski, Phys. Rev. B **54**, 1043 (1996).

² S. Nikitov, P. Tailhades and C. Tsai, J. Magn. Mater. **236**, 320 (2001).

³ S. Neusser and D. Grundler, Adv. Mater. **21**, 2927 (2009).

⁴ V. V. Kruglyak, S. O. Demokritov and D. Grundler, J. Phys. D: Appl. Phys. **43**, 264001 (2010).

⁵ G. Gubbiotti, S. Tacchi, M. Madami, G. Carlotti, A. O. Adeyeye and M. Kostylev, J. Phys. D: Appl. Phys. **43**, 264003 (2010).

⁶ B. Lenk, H. Ulrichs, F. Garbs and M. Münzenberg, Phys. Rep. **507**, 107 (2011).

⁷ M. Krawczyk and D. Grundler, J. Phys. Condens. Matter **26**, 123202 (2014).

⁸ A. V. Chumak, V. I. Vasyuchka, A. A. Serga and B. Hillebrands, Nat. Phys. **11**, 453 (2015).

⁹ F. S. Ma, H. S. Lim, V. L. Zhang, S. C. Ng and M. H. Kuok, Nanoscale Res. Lett. **7**, 1 (2012).

¹⁰ S. Tacchi, G. Duerr, J. W. Klos, M. Madami, S. Neusser, G. Gubbiotti, G. Carlotti, M. Krawczyk and D. Grundler, Phys. Rev. Lett. **109**, 137202 (2012).

¹¹ H. Yu, G. Duerr, R. Huber, M. Bahr, T. Schwarze, F. Brandl and D. Grundler, Nat. Commun. **4**, 2702 (2013).

¹² S. Saha, S. Barman, J. Ding, A. O. Adeyeye and A. Barman, Appl. Phys. Lett. **102**, 242409 (2013).

¹³ M. Mruczkiewicz, M. Krawczyk, G. Gubbiotti, S. Tacchi, Y. A. Filimonov, D. V. Kalyabin, I. V. Lisenkov and S. A. Nikitov, New J. Phys. **15**, 113023 (2013).

- ¹⁴ B. Obry, P. Pirro, T. Brächer, A. V. Chumak, J. Osten, F. Ciubotaru, A. A. Serga, J. Fassbender and B. Hillebrands, *Appl. Phys. Lett.* **102**, 202403 (2013).
- ¹⁵ J. Topp, D. Heitmann, M. P. Kostylev and D. Grundler, *Phys. Rev. Lett.* **104**, 207205 (2010).
- ¹⁶ J. Ding, M. Kostylev and A. O. Adeyeye, *Phys. Rev. Lett.* **107**, 047205 (2011).
- ¹⁷ G. Duerr, K. Thurner, J. Topp, R. Huber and D. Grundler, *Phys. Rev. Lett.* **108**, 227202 (2012).
- ¹⁸ T. Schwarze and D. Grundler, *Appl. Phys. Lett.* **102**, 222412 (2013).
- ¹⁹ R. Huber, M. Krawczyk, T. Schwarze, H. Yu, G. Duerr, S. Albert and D. Grundler, *Appl. Phys. Lett.* **102**, 012403 (2013).
- ²⁰ F. Montoncello, S. Tacchi, L. Giovannini, M. Madami, G. Gubbiotti, G. Carlotti, E. Sirotkin, E. Ahmad, F. Y. Ogrin and V. V. Kruglyak, *Appl. Phys. Lett.* **102**, 024211 (2013).
- ²¹ I. Barsukov, F. M. Römer, R. Meckenstock, K. Lenz, J. Lindner, S. HemkentoKrax, A. Banholzer, M. Körner, J. Grebing, J. Fassbender and M. Farle, *Phys. Rev. B* **84**, 140410 (2011).
- ²² P. Landeros and D. L. Mills, *Phys. Rev. B* **85**, 054424 (2012).
- ²³ X. M. Liu, J. Ding, G. N. Kakazei and A. O. Adeyeye, *Appl. Phys. Lett.* **103**, 062401 (2013).
- ²⁴ R. A. Gallardo, A. Banholzer, K. Wagner, M. Körner, K. Lenz, M. Farle, J. Lindner, J. Fassbender and P. Landeros, *New J. Phys.* **16**, 023015 (2014).
- ²⁵ G. N. Kakazei, X. M. Liu, J. Ding and A. O. Adeyeye, *Appl. Phys. Lett.* **104**, 042403 (2014).
- ²⁶ M. Langer, K. Wagner, T. Sebastian, R. Hübner, J. Grenzer, Y. Wang, T. Kubota, T. Schneider, S. Stienen, K. Lenz, H. Schultheiss, J. Lindner, K. Takanashi, R. E. Arias and J. Fassbender, *Appl. Phys. Lett.* **108**, 102402 (2016).
- ²⁷ R. Cuykendall and D. R. Andersen, *Opt. Lett.* **12**, 542 (1987).
- ²⁸ T. Schneider, A. A. Serga, B. Leven, B. Hillebrands, R. L. Stamps and M. P. Kostylev, *Appl. Phys. Lett.* **92**, 022505 (2008).
- ²⁹ K.-S. Lee and S.-K. Kim, *J. Phys. D: Appl. Phys.* **104**, 053909 (2008).
- ³⁰ A. Khitun, M. Bao and K. L. Wang, *J. Phys. D: Appl. Phys.* **43**, 264005 (2010).
- ³¹ A. Khitun and K. L. Wang, *J. Appl. Phys.* **110**, 034306 (2011).
- ³² A. Berut, A. Arakelyan, A. Petrosyan, S. Ciliberto, R. Dilenschneider and E. Lutz, *Nature* **483**, 187 (2012).
- ³³ A. Khitun, *J. Appl. Phys.* **111**, 054307 (2012).
- ³⁴ N. Sato, K. Sekiguchi and Y. Nozaki, *Appl. Phys. Express* **6**, 063001 (2013).
- ³⁵ M. Jamali, J. H. Kwon, S.-M. Seo, K.-J. Lee and H. Yang, *Sci. Rep.* **3**, 3160 (2013).
- ³⁶ S. Klingler, P. Pirro, T. Brächer, B. Leven, B. Hillebrands and A. V. Chumak, *Appl. Phys. Lett.* **105**, 152410 (2014).
- ³⁷ M. Kostylev, P. Schrader, R. L. Stamps, G. Gubbiotti, G. Carlotti, A. O. Adeyeye, S. Goolaup and N. Singh, *Appl. Phys. Lett.* **92**, 132504 (2008).
- ³⁸ K.-S. Lee, D.-S. Han and S.-K. Kim, *Phys. Rev. Lett.* **102**, 127202 (2009).
- ³⁹ Z. K. Wang, V. L. Zhang, H. S. Lim, S. C. Ng, M. H. Kuok, S. Jain and A. O. Adeyeye, *Appl. Phys. Lett.* **94**, 083112 (2009).
- ⁴⁰ Z. K. Wang, V. L. Zhang, H. S. Lim, S. C. Ng, M. H. Kuok, S. Jain and A. O. Adeyeye, *ACS Nano* **4**, 643 (2010).
- ⁴¹ K. Di, H. S. Lim, V. L. Zhang, M. H. Kuok, S. C. Ng, M. G. Cottam and H. T. Nguyen, *Phys. Rev. Lett.* **111**, 149701 (2013).
- ⁴² M. Krawczyk, S. Mamica, M. Mruczkiewicz, J. W. Kłos, S. Tacchi, M. Madami, G. Gubbiotti, G. Duerr and D. Grundler, *J. Phys. D: Appl. Phys.* **46**, 495003 (2013).
- ⁴³ D. Kumar, J. W. Kłos, M. Krawczyk and A. Barman, *J. Appl. Phys.* **115**, 043917 (2014).
- ⁴⁴ M. Inoue, A. Baryshev, H. Takagi, P. B. Lim, K. Hatafuku, J. Noda and K. Togo, *Appl. Phys. Lett.* **98**, 132511 (2011).
- ⁴⁵ S.-K. Kim, K.-S. Lee and D.-S. Han, *Appl. Phys. Lett.* **95**, 082507 (2009).
- ⁴⁶ M. P. Kostylev, A. A. Serga, T. Schneider, B. Leven and B. Hillebrands, *Appl. Phys. Lett.* **87**, 153501 (2005).
- ⁴⁷ K. Vogt, F. Fradin, J. Pearson, T. Sebastian, S. Bader, B. Hillebrands, A. Hoffmann and H. Schultheiss, *Nat. Commun.* **5**, 3727 (2014).
- ⁴⁸ G. E. W. Bauer, E. Saitoh and B. J. van Wees, *Nat. Mater.* **11**, 391 (2012).
- ⁴⁹ V. E. Demidov, S. Urazhdin, A. Zholud, A. V. Sadovnikov and S. O. Demokritov, *Appl. Phys. Lett.* **106**, 022403 (2015).
- ⁵⁰ M. Vogel, A. V. Chumak, E. H. Waller, T. Langner, V. I. Vasyuchka, B. Hillebrands and G. von Freymann, *Nat. Phys.* **11**, 487 (2015).
- ⁵¹ A. V. Chumak, V. S. Tiberkevich, A. D. Karenowska, A. A. Serga, J. F. Gregg, A. N. Slavin and B. Hillebrands, *Nat. Commun.* **1**, 141 (2010).
- ⁵² S. Demokritov, B. Hillebrands and A. Slavin, *Phys. Rep.* **348**, 441 (2001).
- ⁵³ Y. Roussigné, S. M. Chérif, C. Dugautier and P. Moch, *Phys. Rev. B* **63**, 134429 (2001).
- ⁵⁴ G. Gubbiotti, S. Tacchi, G. Carlotti, N. Singh, S. Goolaup, A. O. Adeyeye and M. Kostylev, *Appl. Phys. Lett.* **90**, 092503 (2007).
- ⁵⁵ S. Tacchi, M. Madami, G. Gubbiotti, G. Carlotti, S. Goolaup, A. O. Adeyeye, N. Singh and M. P. Kostylev, *Phys. Rev. B* **82**, 184408 (2010).
- ⁵⁶ S. Saha, S. Barman, Y. Otani and A. Barman, *Nanoscale* **7**, 18312 (2015).
- ⁵⁷ M. Belmeguenai, M. Gabor, F. Zighem, D. Berling, Y. Roussigné, T. P. Jr., S. Chérif, C. Tiusan, O. Brinza and P. Moch, *J. Mag. Mag. Mater.* **399**, 199 (2016).
- ⁵⁸ M. Langer, F. Röder, R. A. Gallardo, T. Schneider, S. Stienen, C. Gatel, R. Hübner, L. Bischoff, K. Lenz, J. Lindner, P. Landeros and J. Fassbender, *ArXiv*: 1609.00342 (2016).
- ⁵⁹ P. E. Tannenwald and M. H. Seavey, *Phys. Rev.* **105**, 377 (1957).
- ⁶⁰ M. H. Seavey and P. E. Tannenwald, *Journal of Applied Physics* **30**, S227 (1959).
- ⁶¹ A. Vansteenkiste, J. Leliaert, M. Dvornik, M. Helsen, F. Garcia-Sanchez and B. Van Waeyenberge, *AIP Adv.* **4**, 107133 (2014).
- ⁶² R. D. McMichael and M. D. Stiles, *J. Appl. Phys.* **97** (2005).
- ⁶³ M. Körner, K. Lenz, R. A. Gallardo, M. Fritzsche, A. Mücklich, S. Facsko, J. Lindner, P. Landeros and J. Fassbender, *Phys. Rev. B* **88**, 054405 (2013).
- ⁶⁴ B. A. Kalinikos and A. N. Slavin, *J. Phys. C* **19**, 7013 (1986).
- ⁶⁵ C. Bayer, J. Jorzick, B. Hillebrands, S. O. Demokritov,

- R. Kouba, R. Bozinoski, A. N. Slavin, K. Y. Guslienکو, D. V. Berkov, N. L. Gorn and M. P. Kostylev, Phys. Rev. B **72**, 064427 (2005).
- ⁶⁶ J. Lindner, T. Toliński, K. Lenz, E. Kosubek, H. Wende, K. Baberschke, A. Ney, T. Hesjedal, C. Pampuch, R. Koch, L. Däweritz and K. Ploog, J. Mag. Mag. Mater. **277**, 159 (2004).
- ⁶⁷ M. Krawczyk and H. Puzskarski, Phys. Rev. B **77**, 054437 (2008).
- ⁶⁸ M. L. Sokolovskyy and M. Krawczyk, J. Nanopart. Res. **13**, 6085 (2011).
- ⁶⁹ J. W. Kłos, D. Kumar, J. Romero-Vivas, H. Fangohr, M. Franchin, M. Krawczyk and A. Barman, Phys. Rev. B **86**, 184433 (2012).
- ⁷⁰ R. A. Gallardo, M. Langer, A. Roldán-Molina, T. Schneider, K. Lenz, J. Lindner and P. Landeros, ArXiv: 1610.04176 (2016).